



FZT558

400V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

Features

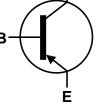
- BVcEo > -400V
- Ic = -200mA High Continuous Current
- Excellent hFE Characteristics up to -100mA
- Low Saturation Voltage VcE(sat) < -200mV @ -20mA
- Complementary NPN Type: FZT458
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

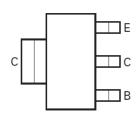
- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)







Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

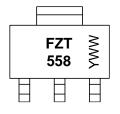
Part Number	Compliance	Paakaga	Marking Reel Size (inches) Tape Width (mm) Packing		king		
Fait Nulliber	Compliance	Package	Warking	Reel Size (Iliches)	rape widin (ililii)	Qty.	Carrier
FZT558TA	Standard	SOT223 (Type DN)	FZT558	7	12	1,000	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223 (Type DN)



FZT558 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 2 = 2022) WW or $\overline{W}W = Week Code (01 to 53)$



Absolute Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-400	V
Collector-Emitter Voltage	Vceo	-400	V
Emitter-Base Voltage	VEBO	-7	V
Continuous Collector Current	lc	-200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Dower Dissipation	(Note 5)	D-	2	W
Power Dissipation	(Note 6)	P _D	3	W
Thermal Decistores, Junction to Ambient	(Note 5)	Б	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note	Rejl	19.41	°C/W	
Operating and Storage Temperature Range	T_{J}, T_{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

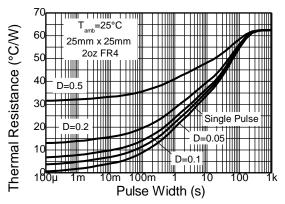
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

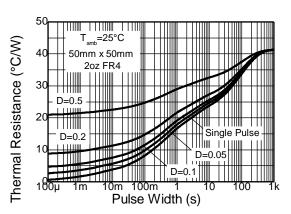
Notes:

- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- Same as note (5), except the device is mounted on 50mm x 50mm single sided 2oz weight copper.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



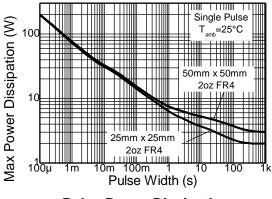
Thermal Characteristics and Derating Information

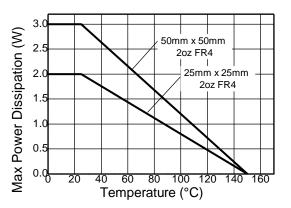




Transient Thermal Impedance

Transient Thermal Impedance





Pulse Power Dissipation

Derating Curve



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-400	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BVceo	-400	_	_	V	Ic = -1mA
Emitter-Base Breakdown Voltage	BVEBO	-7	_	_	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	_	_	-100	nA	V _{CB} = -320V
Collector Cut-Off Current	Ices	_	_	-100	nA	Vce = -320V
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	V _{EB} = -5V
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	_	_	-0.2	V	Ic = -20mA, I _B = -2mA
Concolor Entitler Cataration Voltage (Note 5)	V CE(Sat)	_	_	-0.5	•	$I_C = -50 \text{mA}$, $I_B = -6 \text{mA}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	_	_	-0.9	V	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	_	_	-0.9	V	Ic = -50mA, VcE = -10V
DC Current Transfer Static Ratio (Note 9)	hfE	100 100 15	=	300 —	_	Ic = -1mA, VcE = -10V Ic = -50mA, VcE = -10V Ic = -100mA, VcE = -10V
Transitional Frequency (Note 9)	fτ	50	_	_	MHz	$V_{CE} = -20V$, $I_{C} = -10mA$ f = 20MHz
Output Capacitance (Note 9)	Cobo	_	_	5	pF	V _{CB} = -20V, f = 1MHz
Switching Time	ton		95		ns	$I_C = -50 \text{mA}, V_C = -100 \text{V}$
Ownering Time	t _{off}		1,600		113	$I_{B1} = 5mA$, $I_{B2} = -10mA$

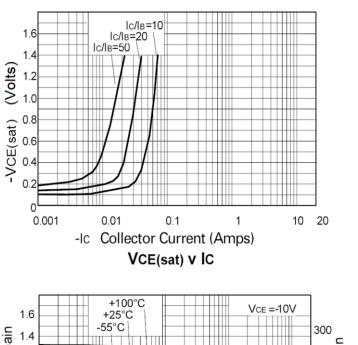
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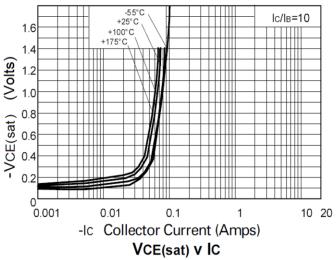
Note:

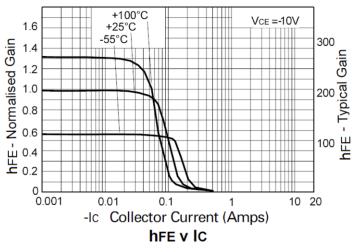
9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

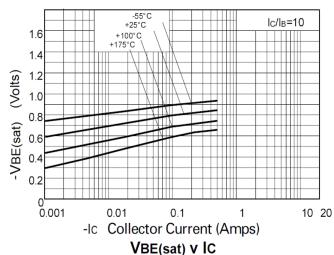


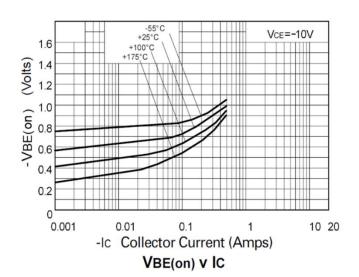
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









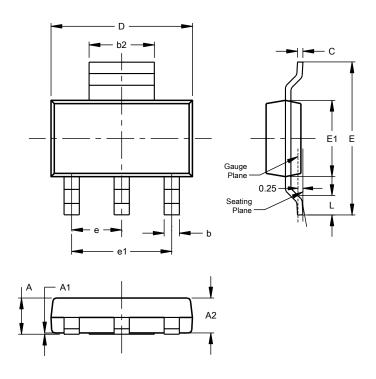




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

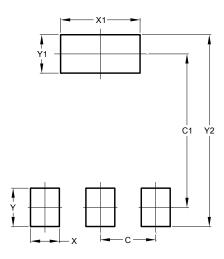


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
V2	8 00



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